

TOSHIBA Transistor Silicon PNP · NPN Epitaxial Type  
(PCT process) (Bias Resistor built-in Transistor)

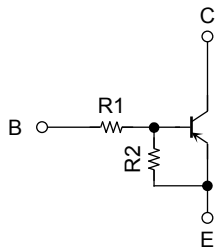
# RN49A1

Switching, Inverter Circuit, Interface Circuit and  
Driver Circuit Applications

- Two devices are incorporated into an Ultra-Super-Mini (6 pin) package.
- Incorporating a bias resistor into a transistor reduces parts count. Reducing the parts count enable the manufacture of ever more compact equipment and save assembly cost.

## Equivalent Circuit and Bias Resistor Values

**Q1**



Q1

R1: 2.2 kΩ, R2: 47 kΩ

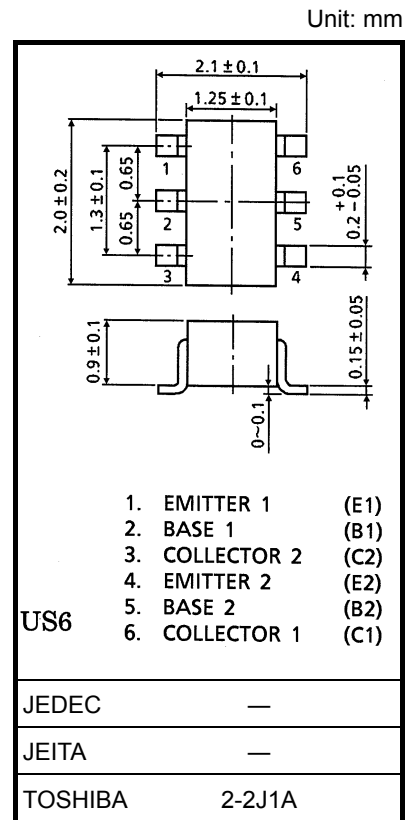
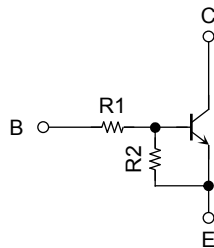
Q2

R1: 22 kΩ, R2: 47 kΩ

Q1:RN2105F equivalent

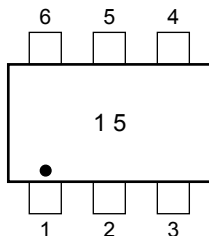
Q2:RN1108F equivalent

**Q2**

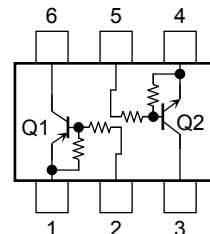


Weight: 0.006g (typ.)

## Marking



## Equivalent Circuit (top view)



## Absolute Maximum Ratings (Ta = 25°C) (Q1)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CB0</sub>	-50	V
Collector-emitter voltage	V <sub>CEO</sub>	-50	V
Emitter-base voltage	V <sub>EBO</sub>	-5	V
Collector current	I <sub>C</sub>	-100	mA

## Absolute Maximum Ratings (Ta = 25°C) (Q2)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CB0</sub>	50	V
Collector-emitter voltage	V <sub>CEO</sub>	50	V
Emitter-base voltage	V <sub>EBO</sub>	7	V
Collector current	I <sub>C</sub>	100	mA

## Absolute Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Rating	Unit
Collector power dissipation	P <sub>C</sub> (Note 1)	200	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature range	T <sub>stg</sub>	-55~150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Total rating

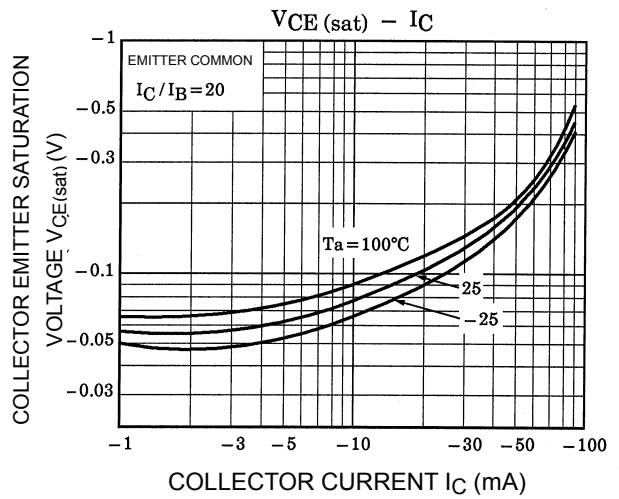
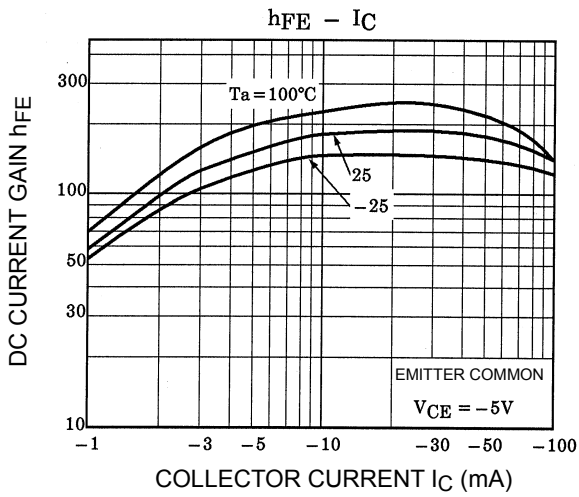
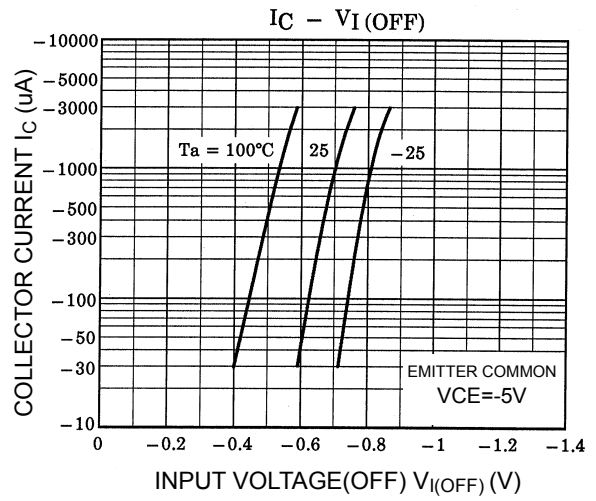
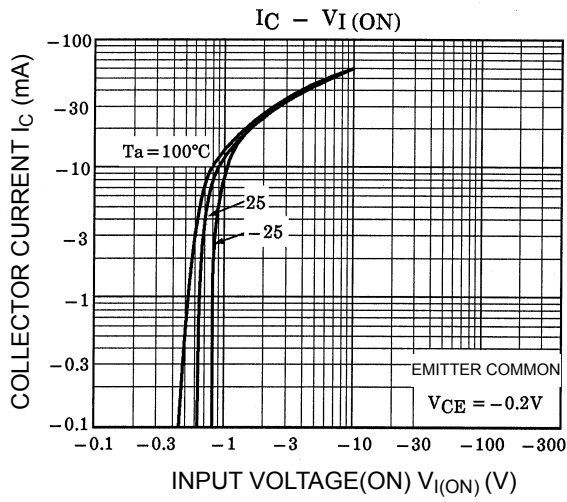
## Electrical Characteristics (Ta = 25°C) (Q1)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = -50\text{ V}, I_E = 0$	—	—	-100	nA
	$I_{CEO}$	$V_{CE} = -50\text{ V}, I_B = 0$	—	—	-500	
Emitter cut-off current	$I_{EBO}$	$V_{EB} = -5\text{ V}, I_C = 0$	-0.078	—	-0.145	mA
DC current gain	$h_{FE}$	$V_{CE} = -5\text{ V}, I_C = -10\text{ mA}$	80	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -5\text{ mA}, I_B = -0.25\text{ mA}$	—	-0.1	-0.3	V
Input voltage (ON)	$V_I(ON)$	$V_{CE} = -0.2\text{ V}, I_C = -5\text{ mA}$	-0.6	—	-1.1	V
Input voltage (OFF)	$V_I(OFF)$	$V_{CE} = -5\text{ V}, I_C = -0.1\text{ mA}$	-0.5	—	-0.8	V
Transition frequency	$f_T$	$V_{CE} = -10\text{ V}, I_C = -5\text{ mA}$	—	200	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = -10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3	—	pF
Input resistance	R1	—	1.54	2.2	2.86	kΩ
Resistance ratio	R1/R2	—	0.0421	0.0468	0.0515	—

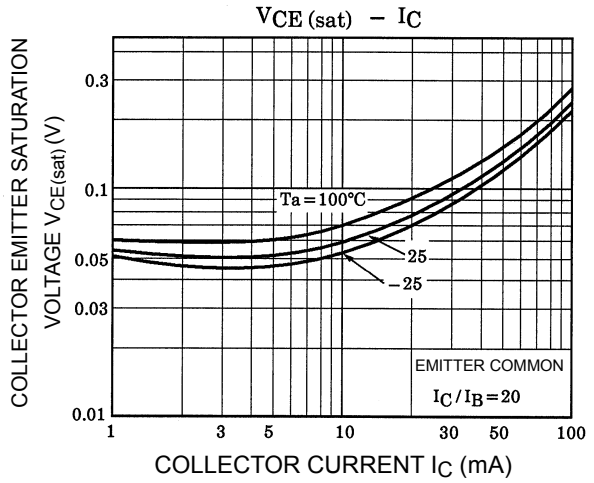
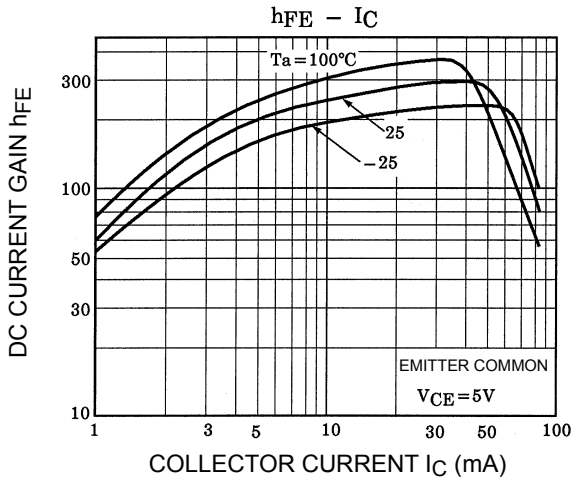
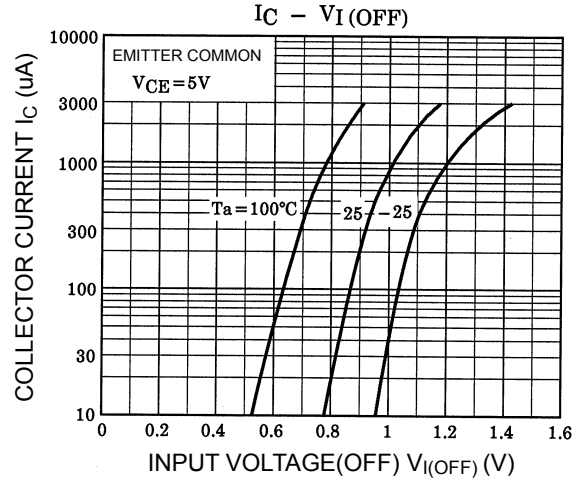
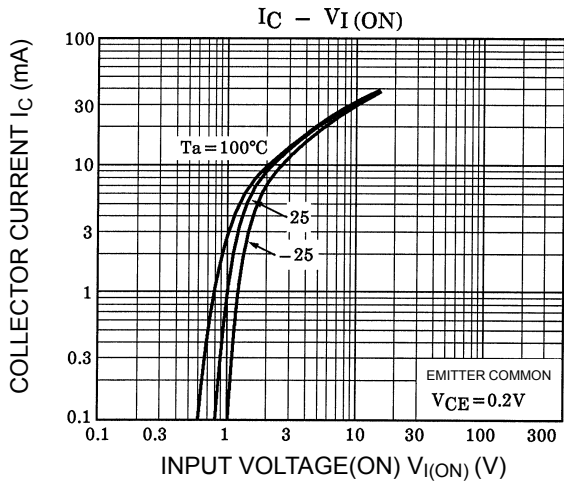
## Electrical Characteristics (Ta = 25°C) (Q2)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = 50\text{ V}, I_E = 0$	—	—	100	nA
	$I_{CEO}$	$V_{CE} = 50\text{ V}, I_B = 0$	—	—	500	
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 7\text{ V}, I_C = 0$	0.078	—	0.145	mA
DC current gain	$h_{FE}$	$V_{CE} = 5\text{ V}, I_C = 10\text{ mA}$	80	—	—	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 5\text{ mA}, I_B = 0.25\text{ mA}$	—	0.1	0.3	V
Input voltage (ON)	$V_I(ON)$	$V_{CE} = 0.2\text{ V}, I_C = 5\text{ mA}$	1.0	—	2.6	V
Input voltage (OFF)	$V_I(OFF)$	$V_{CE} = 5\text{ V}, I_C = 0.1\text{ mA}$	0.6	—	1.16	V
Transition frequency	$f_T$	$V_{CE} = 10\text{ V}, I_C = 5\text{ mA}$	—	250	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3	—	pF
Input resistance	R1	—	1.54	22	2.86	kΩ
Resistance ratio	R1/R2	—	0.421	0.468	0.515	—

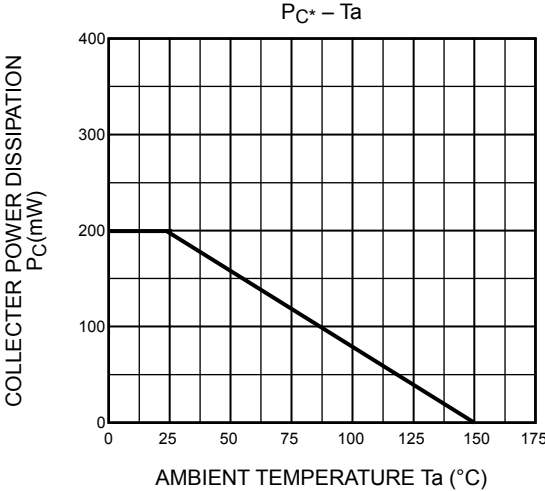
**Q1**



Q2



**Q1,Q2 COMMON**



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20070701-EN GENERAL

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